

20 V, single P-channel Trench MOSFET 14 August 2012

Product data sheet

1. Product profile

1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Fast switching
- Trench MOSFET technology
- 2 kV ESD protection

1.3 Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-5.7	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -3 A; T _j = 25 °C		-	41	46	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G (T
4	S	source	TSOP6 (SOT457)	
5	D	drain		
6	D	drain		S 017aaa259

3. Ordering information

Table 3. Ordering inf	formation		
Type number	Package		
	Name	Description	Version
PMN42XPE	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMN42XPE	WE

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-5.7	А
		V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-4	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-2.9	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-16	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	500	mW
			[1]	-	1310	mW
		T _{sp} = 25 °C		-	8330	mW

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Symbol	Parameter	Conditions		Min	Мах	Unit
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	in diode	L				
l _S	source current	T _{amb} = 25 °C	[1]	-	-1.4	А
ESD maxim	um rating	·				
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.

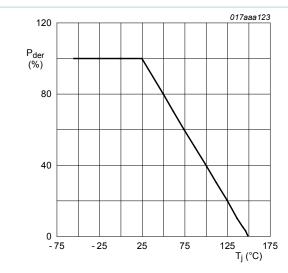


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

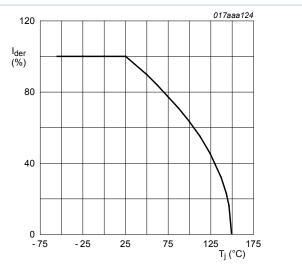
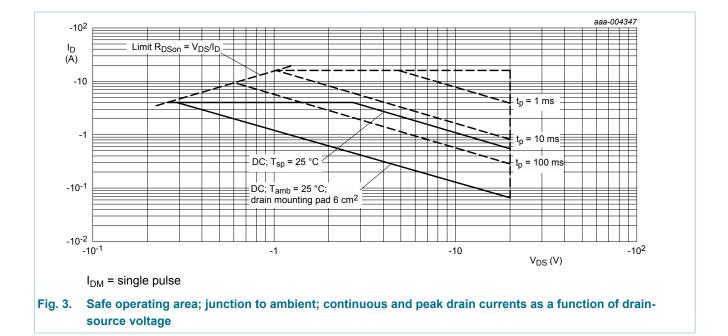


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}\text{C})}} \times 100 ~\%$$

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6. Thermal characteristics

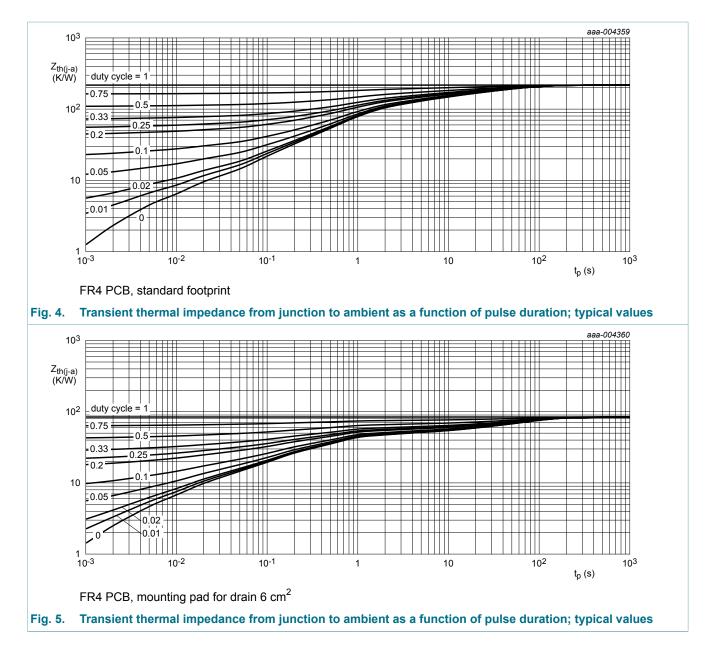
Table 6. 1	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistan from junction to ambient	thermal resistance	in free air	[1]	-	216	250	K/W
	-		[2]	-	83	95	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	51	60	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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7. Characteristics

Table 7. C	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					_
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	-0.75	-1	-1.25	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{DS} = -20 V; V_{GS} = 0 V; T_{amb} = 150 °C	-	-	-10	μA
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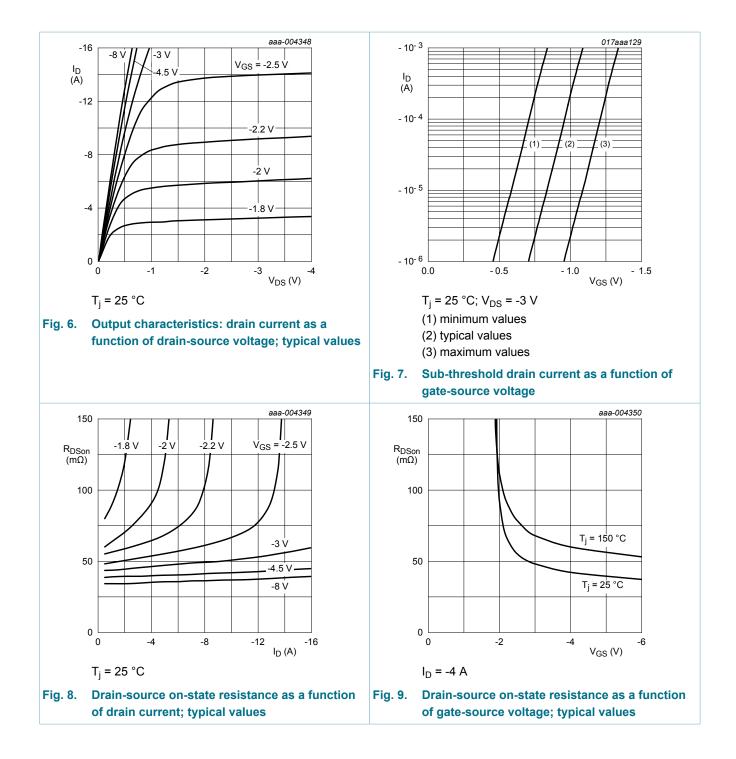
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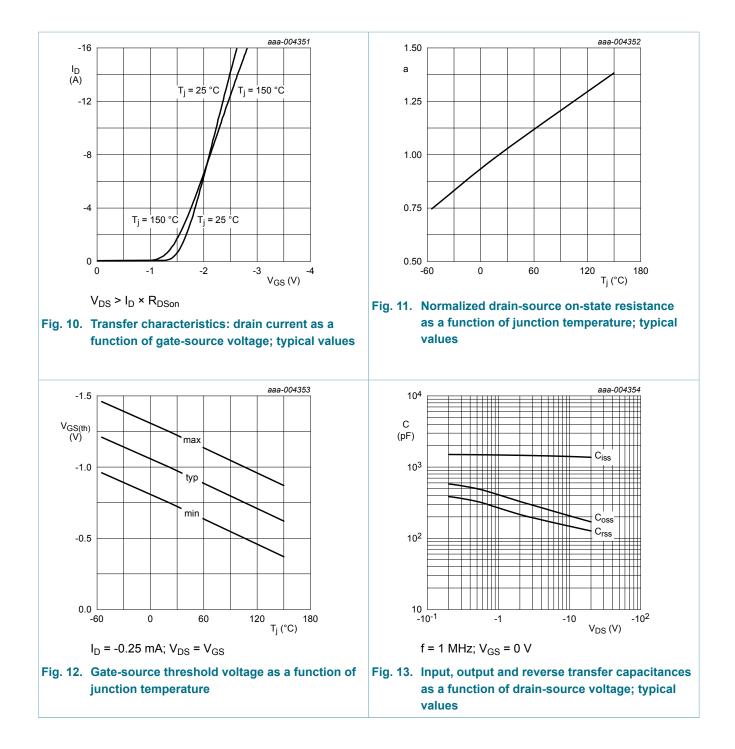
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GSS}	gate leakage current	V_{GS} = 12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -3 A; T _j = 25 °C	-	41	46	mΩ
	resistance	V_{GS} = -4.5 V; I _D = -3 A; T _j = 150 °C	-	56	64	mΩ
		V_{GS} = -2.5 V; I _D = -3 A; T _j = 25 °C	-	56	64	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -4 A; T _j = 25 °C	-	12.5	-	S
Dynamic cl	naracteristics	· · · · ·	I			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I_{D} = -4 A; V_{GS} = -4.5 V;	-	11.5	17.3	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.7	-	nC
Q _{GD}	gate-drain charge		-	2.4	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	1410	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	207	-	pF
C _{rss}	reverse transfer capacitance		-	148	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -4 A; V _{GS} = -4.5 V;	-	17	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	27	-	ns
t _{d(off)}	turn-off delay time		-	33	-	ns
t _f	fall time		-	27	-	ns
Source-dra	in diode	· · ·		1		
V _{SD}	source-drain voltage	I _S = -1.2 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V

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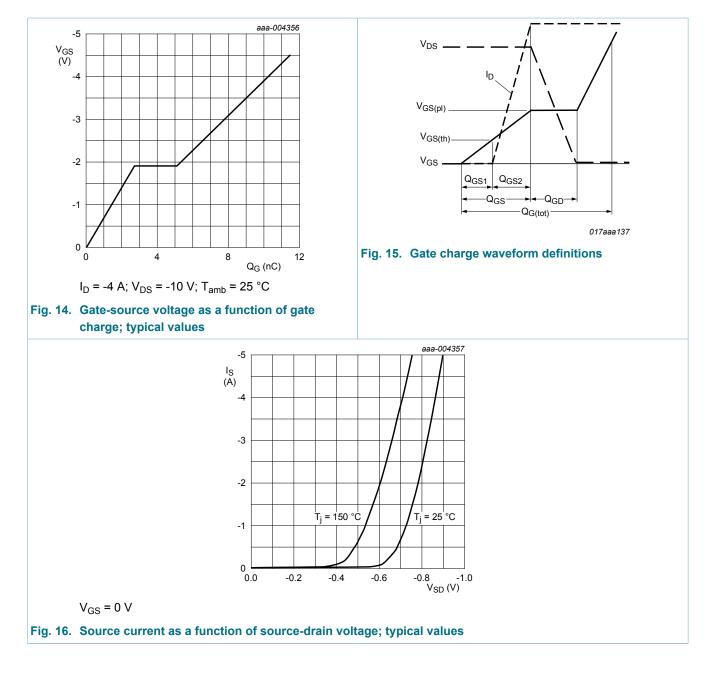
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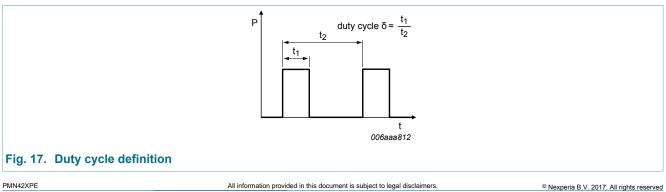


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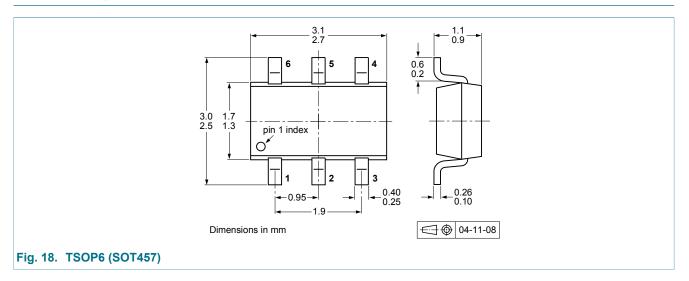


8. Test information

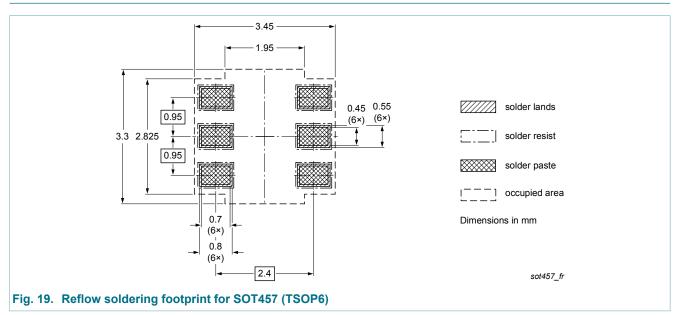


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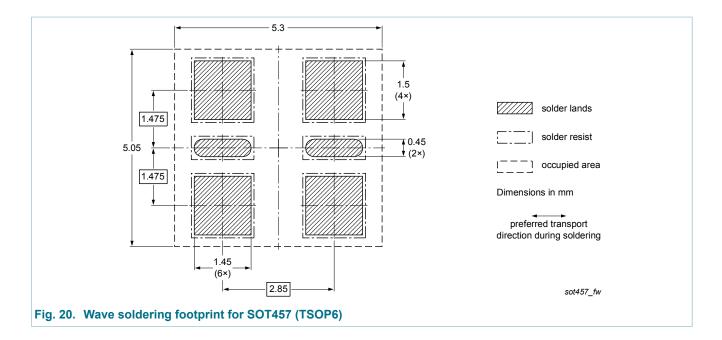
9. Package outline



10. Soldering



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11. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PMN42XPE v.1	20120814	Product data sheet	-	-	

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12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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